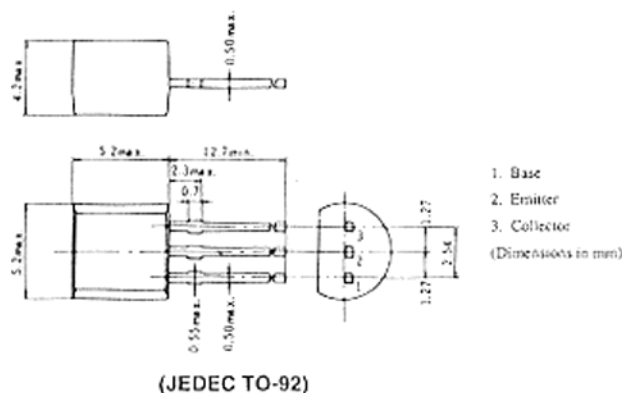


2SC2512

SILICON NPN EPITAXIAL
VHF AMPLIFIER
VHF TV TUNER MIXER

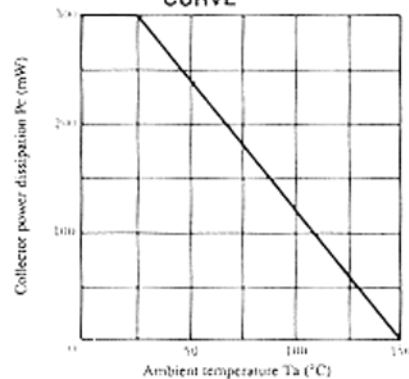


1. Base
 2. Emitter
 3. Collector
- (Dimensions in mm)

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Item	Symbol	2SC2512	Unit
Collector to base voltage	V _{CB0}	30	V
Collector to emitter voltage	V _{CE0}	20	V
Emitter to base voltage	V _{EB0}	3	V
Collector current	I _C	50	mA
Collector power dissipation	P _C	300	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

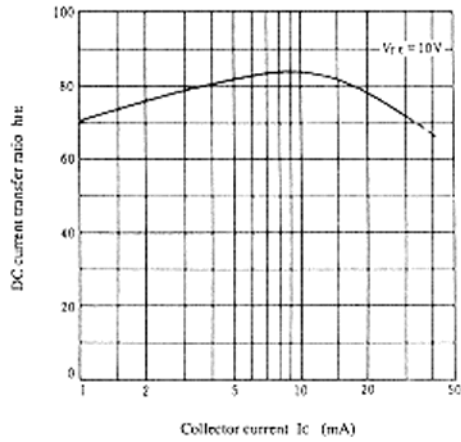
MAXIMUM COLLECTOR DISSIPATION CURVE



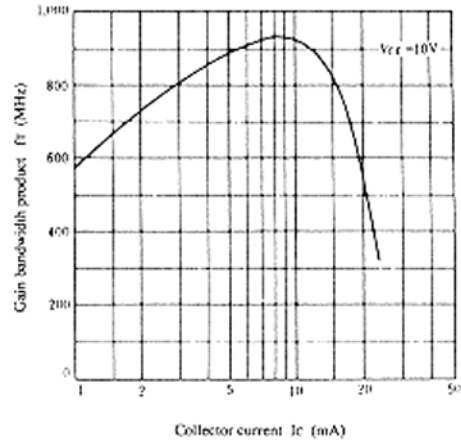
■ ELECTRICAL CHARACTERISTICS (Ta=25°C)

Item	Symbol	Test Condition	min.	typ.	max.	Unit
Collector to base breakdown voltage	V _{(BR)CBO}	I _C = 10μA, I _E = 0	30	—	—	V
Collector to emitter breakdown voltage	V _{(BR)CEO}	I _C = 1mA, R _{BE} = ∞	20	—	—	V
Emitter to base breakdown voltage	V _{(BR)EBO}	I _E = 10μA, I _C = 0	3	—	—	V
Collector cutoff current	I _{CB0}	V _{CB} = 10V, I _E = 0	—	—	0.5	μA
Collector to emitter saturation voltage	V _{CE(sat)}	I _C = 20mA, I _B = 4mA	—	—	1	V
DC current transfer ratio	h _{FE}	V _{CE} = 10V, I _C = 10mA	30	—	—	
Reverse transfer capacitance	C _{re}	V _{CB} = 10V, Emitter common, f = 1MHz	—	0.35	0.45	pF
Gain bandwidth product	f _r	V _{CE} = 10V, I _C = 10mA	600	900	—	MHz
Base time constant	τ _{b0} · C _c	V _{CB} = 10V, I _C = 5mA, f = 31.8MHz	—	—	20	ps
Conversion gain	CG	V _{CC} = 12V, I _C = 2mA, f _{in} = 200MHz f _{osc} = 260MHz, f _{out} = 60MHz	16	20	—	dB
Noise figure	NF	V _{CC} = 12V, I _C = 2mA, f _{osc} = 260MHz R _g = 50Ω, f _{in} = 200MHz	—	3.8	5.5	dB

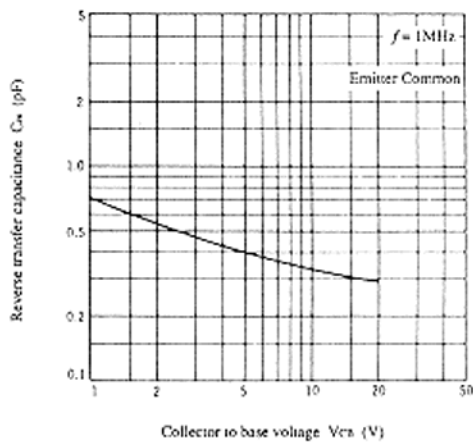
DC CURRENT TRANSFER RATIO VS. COLLECTOR CURRENT



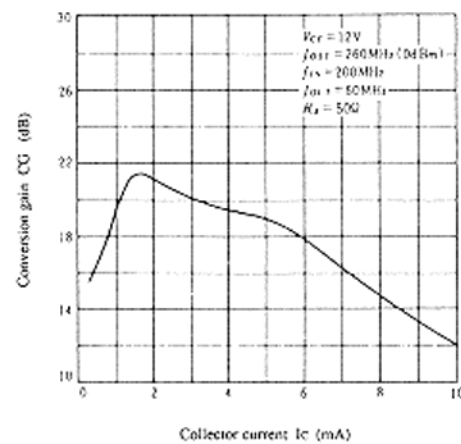
GAIN BANDWIDTH PRODUCT VS. COLLECTOR CURRENT



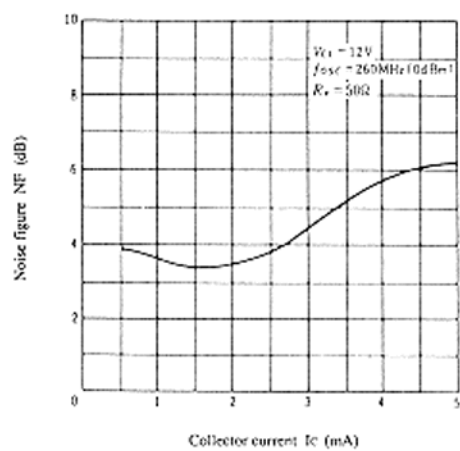
REVERSE TRANSFER CAPACITANCE VS. COLLECTOR TO BASE VOLTAGE



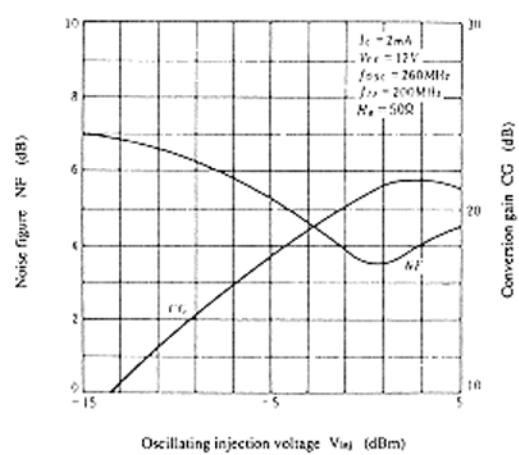
CONVERSION GAIN VS. COLLECTOR CURRENT



NOISE FIGURE VS. COLLECTOR CURRENT

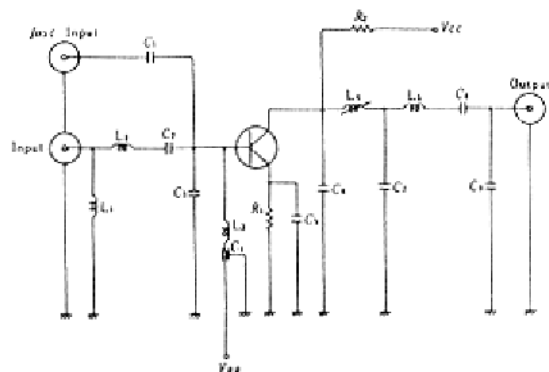


NOISE FIGURE, CONVERSION GAIN VS. OSCILLATING INJECTION VOLTAGE



2SC2512

CONVERSION GAIN, NOISE FIGURE TEST CIRCUIT



- R1 : 330Ω (1/4W)
- R2 : 560Ω (1/4W)
- L1 : φ0.8mm Copper wire with Enamel 8 Turns
inside dia φ3mm
- L2 : φ0.8mm Copper wire with Enamel 5 Turns
inside dia φ3mm
- L3 : φ0.5mm Copper wire with Enamel 3.5 Turns
inside dia φ3mm
- L4 : Outside dia φ5mm used Ferrite Core, φ0.2mm
Copper wire with Enamel 6.5 Turns
- L5 : φ0.2mm Copper wire with Enamel 13 Turns
inside dia φ5mm

Parts Specification

- C1 : 1.5pF
- C2 : 57pF
- C3 : 17pF
- C4 : 1000pF
- C5 : 2200pF
- C6 : 22pF
- C7 : 80pF
- C8 : 18pF
- C9 : 20pF